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INFORMATION DISCLOSURE STATEMENT TRANSMITTAL To Commissioner For Patents Enclosed herewith is a Form PTO-1449, any required copies of documents listed thereon, and any concise explanation of their relevance is indicated below per 37 CFR 1.97.	Application Number	
	Filing Date	
	First Named Inventor	MEUNIER-BEILLARD, PHILIPPE
	Group Art Unit	
	Examiner Name	
	Atty. Docket Number	US04 0056 US2

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number No.-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
	1	US- 5 506 427	04/09/1996	IMAI ET AL.	
	2	US- 5 773 350	06/30/1998	HERBERT ET AL.	
		US-			
		US-			
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FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number (ctry ³ -no.-kind ² , if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of cited document	Pages, Columns Lines, Where Relevant Passages or Relevant Figures Appear
	1	JP 02 203533	10/26/1990	TOSHIBA CORP	
	2	JP 02 205033	10/26/1990	HITACHI LTD	

NON-PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in capital letters), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ⁴
	1	DONKER J. J. T. M. : "VERTICAL PROFILE OPTIMISATION OF A SELF-ALIGNED SiGeC HBT PROCESS WITH AN n-CAP EMITTER"; BIPOLAR/BiCMOS CIRCUIT AND TECHNOLOGY MEETING 2003; PP 111-114.	
	2	P. D. AGNELLO : "GROWTH RATE ENHANCEMENT OF HEAVY n- AND p-TYPE DOPED SILICON DEPOSITED BY ATMOSPHERIC-PRESSURE CHEMICAL VAPOR DEPOSITION AT LOW TEMPERATURE"; JOURNAL ELECTROCHEM SOCIETY VOL. 140 NO. 9; 1993 PP 2703.	

Examiner Signature	/John Doyle/	Date Considered	04/30/2009
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* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the